

ON THE SILICON TRACKER

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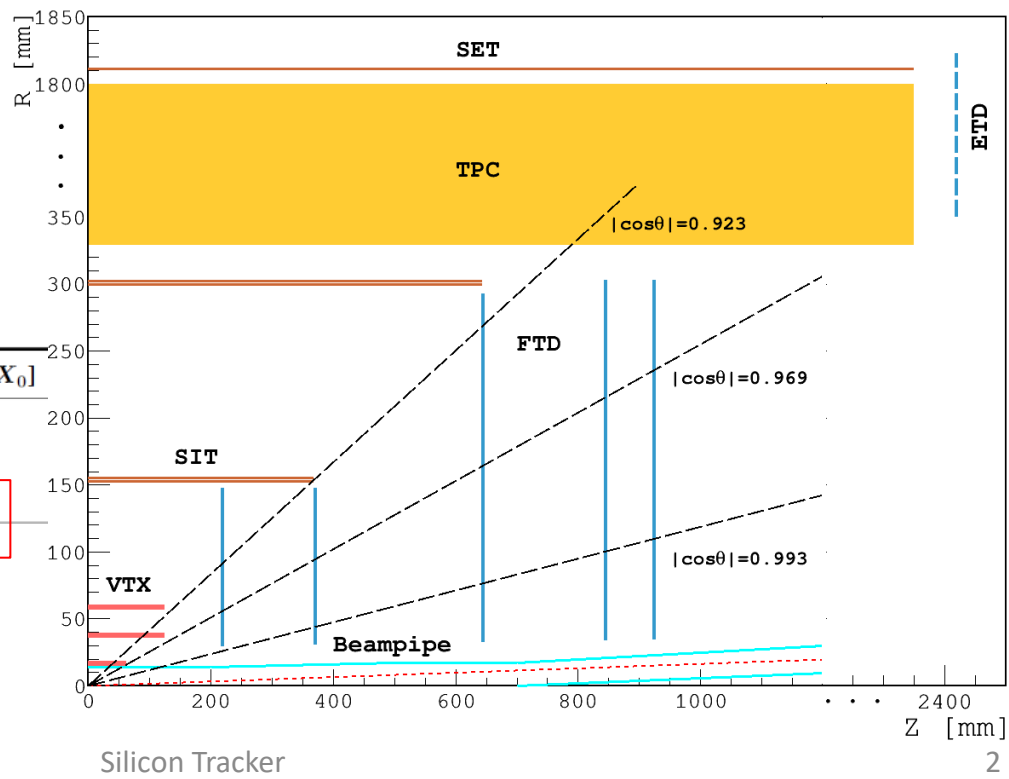
REQUIREMENTS

- Large area tracking system to deliver high track momentum resolution
- Silicon tracker: multiple high precision measurements along the track particle trajectory;
 - Spatial resolution $\sigma_{r\phi} \sim 7 \mu\text{m}$; time resolution $\sigma_t \sim 10 \text{ ns}$; low material budget, low cost

Silicon envelope

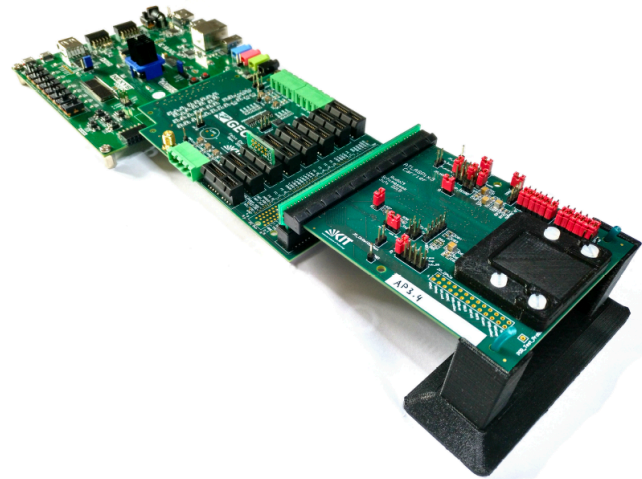
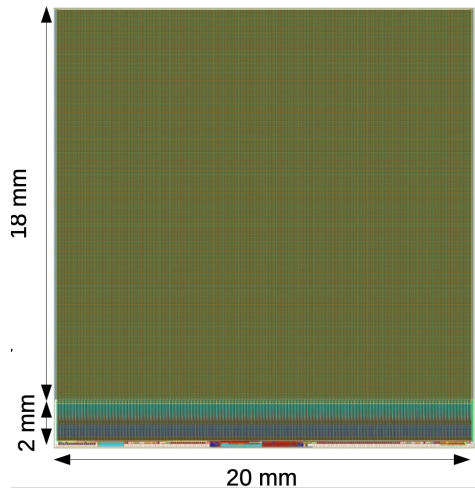
Long barrel

Detector		Radius R [mm]	$\pm z$ [mm]	Material budget [X_0]
SIT	Layer 1	153	371.3	0.65%
	Layer 2	300	664.9	0.65%
SET	Layer 3	1811	2350	0.65%



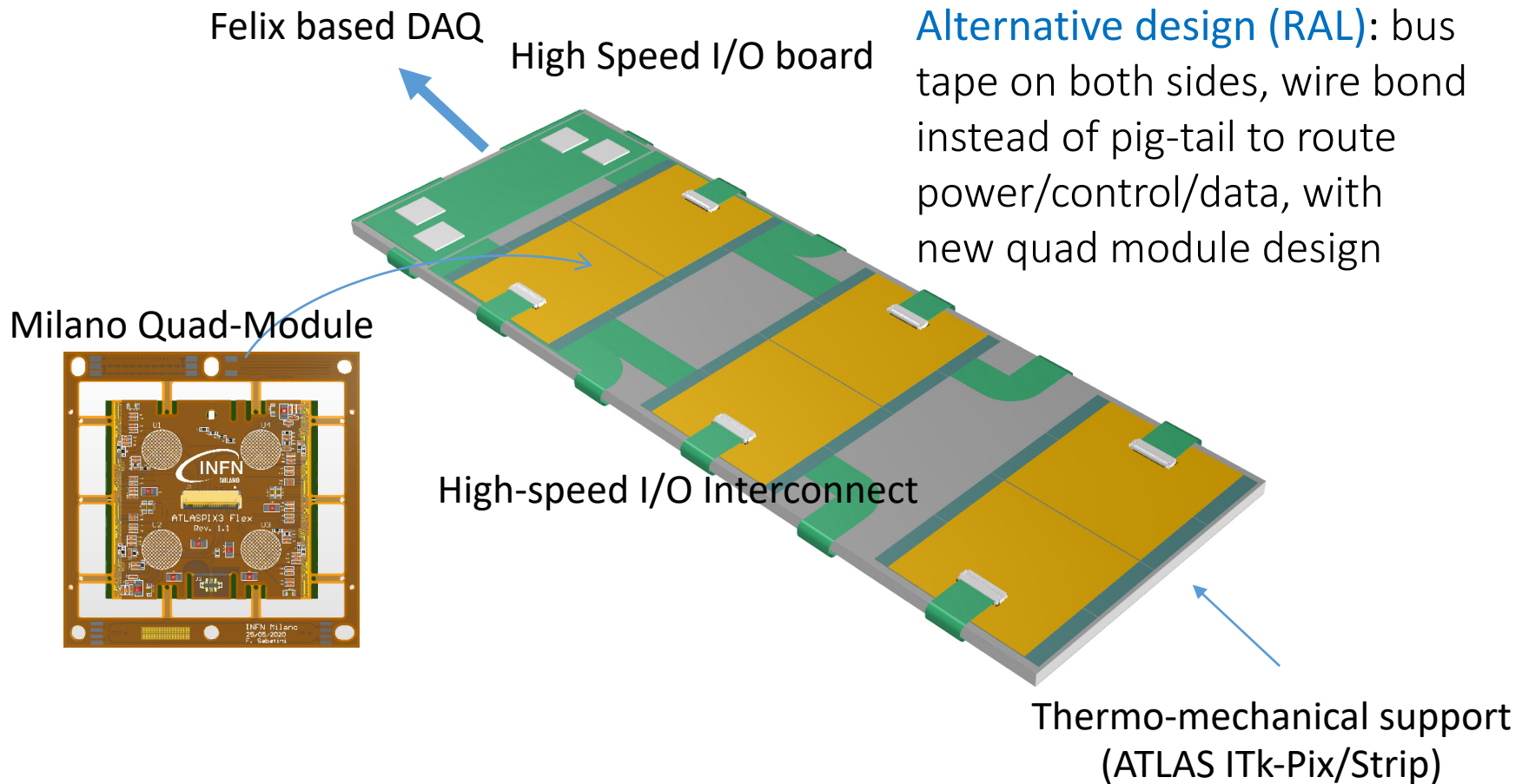
SENSOR TECHNOLOGY: HV-CMOS

- HV-CMOS sensor can provide an alternative solution to conventional microstrip detectors for a large-area tracking system
 - lower cost, lower material budget, higher performance
- Adopted for Mu3e (MuPix), explored but dropped for the ATLAS ITk-Pixel/Strip (**project time constraints**), considered for the LHCb tracker upgrade, CLIC and CEPC silicon tracker + **several other applications**
- **ATLASPix3** for performance evaluation and module/stave prototyping; next generation fabricated with a domestic process being considered



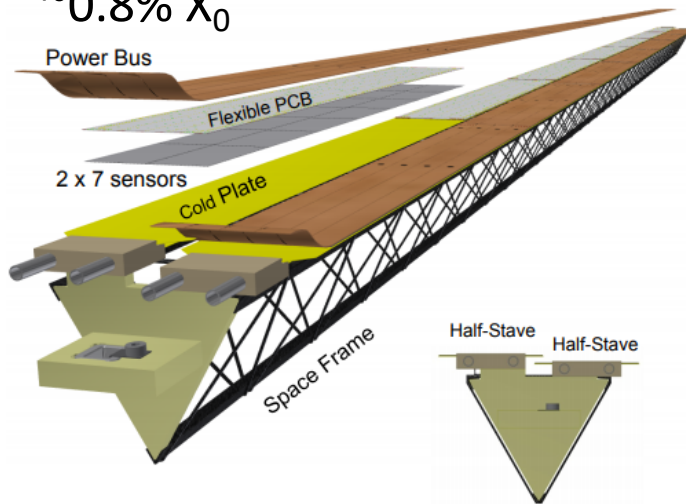
BUILDING A DEMONSTRATOR

- To build a **short stave** to demonstrate the system feasibility → capability to readout multiple modules (**reusing ATLAS designs/components**)

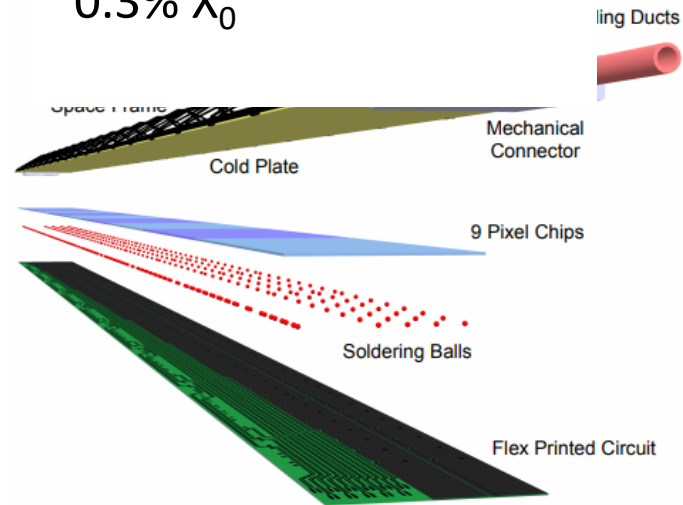


SUPPORTING STRUCTURES

ALICE Outer Layer Stave ~0.8% X_0

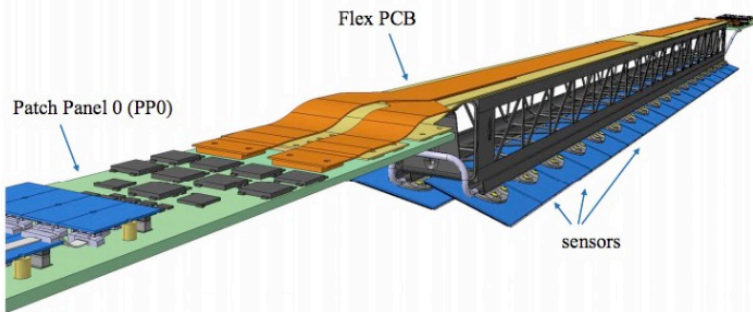


ALICE Inner Layer Stave ~0.3% X_0



ATLAS-ITK: 0.5% X_0 ITK alpine stave (+module)

ATLAS IBL: 0.7% X_0 IBL stave, (+module)



CEPC design target:

0.65% X_0 for stave + modules

Crucial elements:

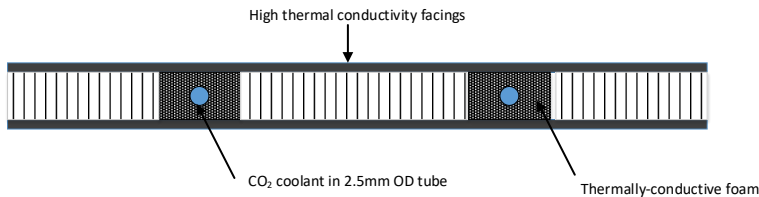
- Light-weighted carbon truss structure
- Al based flex (prototype with Cu)

Possibility to produce them in China to be explored

SUPPORTING STRUCTURE FOR DEMONSTRATOR

ATLAS ITk Strip

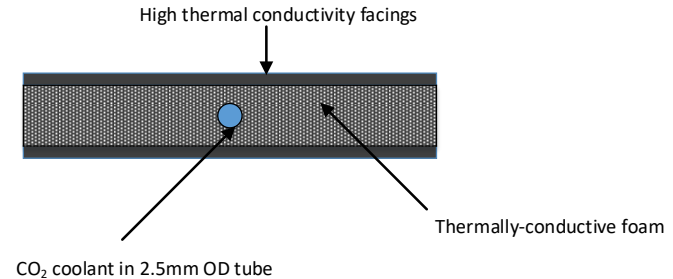
Power dissipation: 60 mW/cm²



Support, electrical services & cooling,
Material budget: 0.7%X₀

ATLAS ITk-Pixel

Power dissipation: 700 mW/cm²



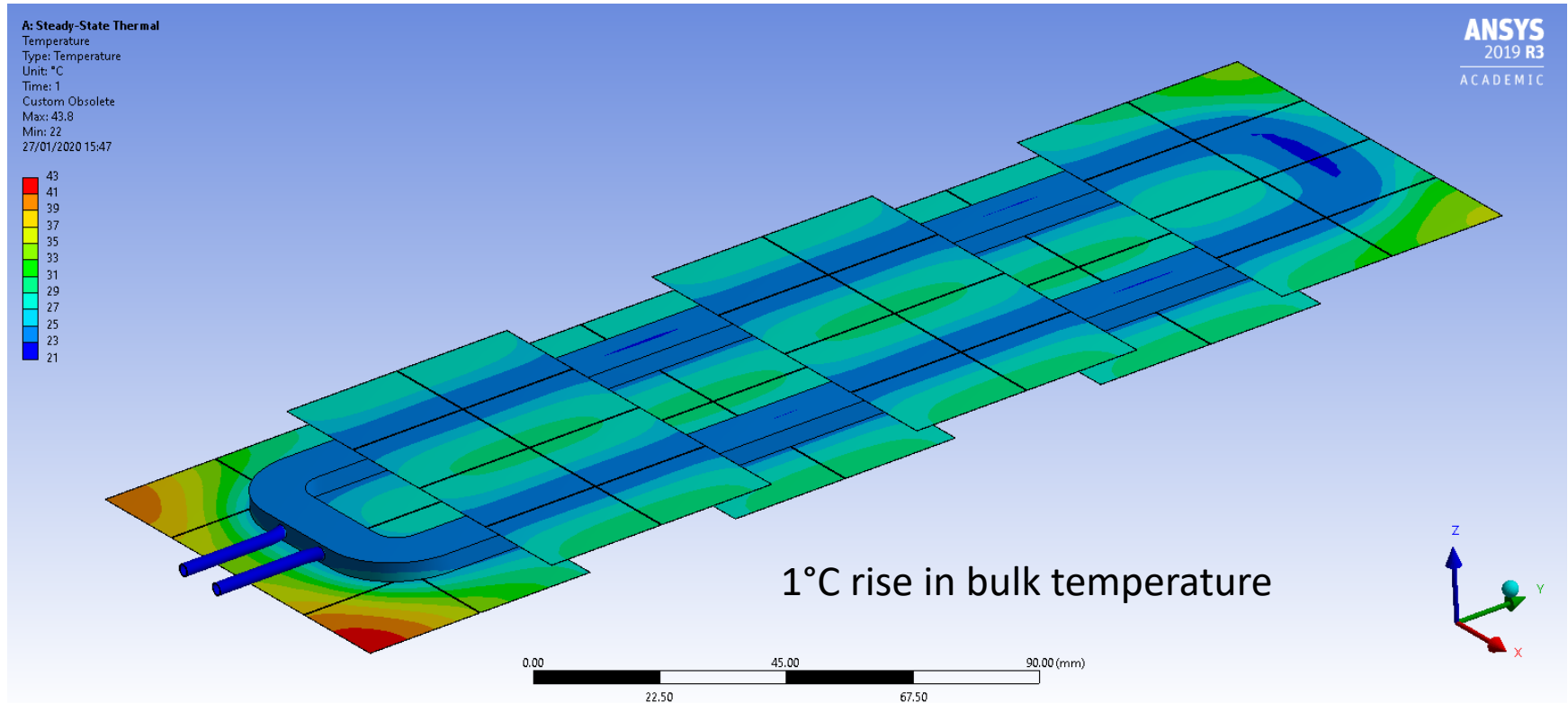
Support, electrical services & cooling,
Material budget: 1.5%X₀

Demonstrator



Can be scaled up to
a full barrel stave

Parameter	Value	Units
Active Length	248.2	mm
Active Width	80.6	mm
Number of Quad Modules	12	
Number of HV-CMOS ASICs	48	
HV-CMOS ASIC Dimensions	20 x 22	mm
Total HV-CMOS area	211.2	cm ²
Total Power (@0.14W/cm ²)	27	W

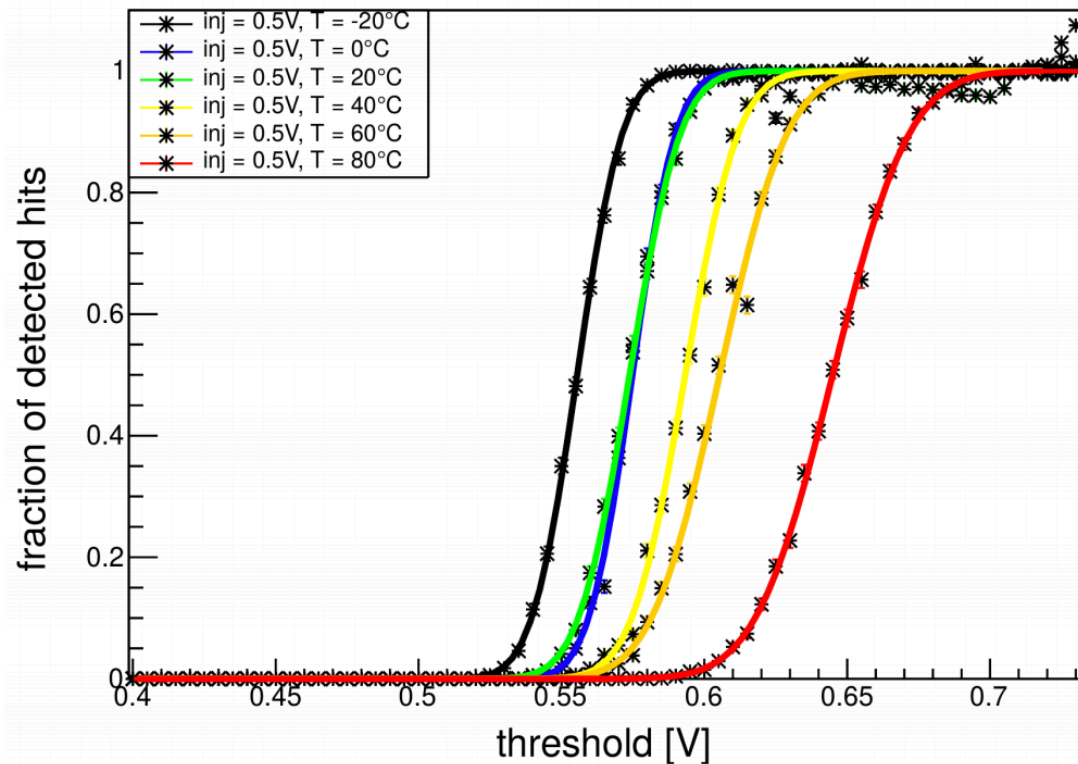


- ATLAS ITk-Strip structure with water cooling (not CO₂) to cope with total power dissipation of 28 W (ATLASPix3) + ? (I/O board)
- Assume for $T_{ASIC} = 30\text{ °C}$ and on/off temperature rise $\Delta T_{Off/On} = 20\text{ °C}$

COOLING & TEMPERATURE CONTROL

- Temperature dependent performance of HV-CMOS sensors; **temperature variation tolerance?**

Mupix8: Temperature Dependence



MATERIAL BUDGET

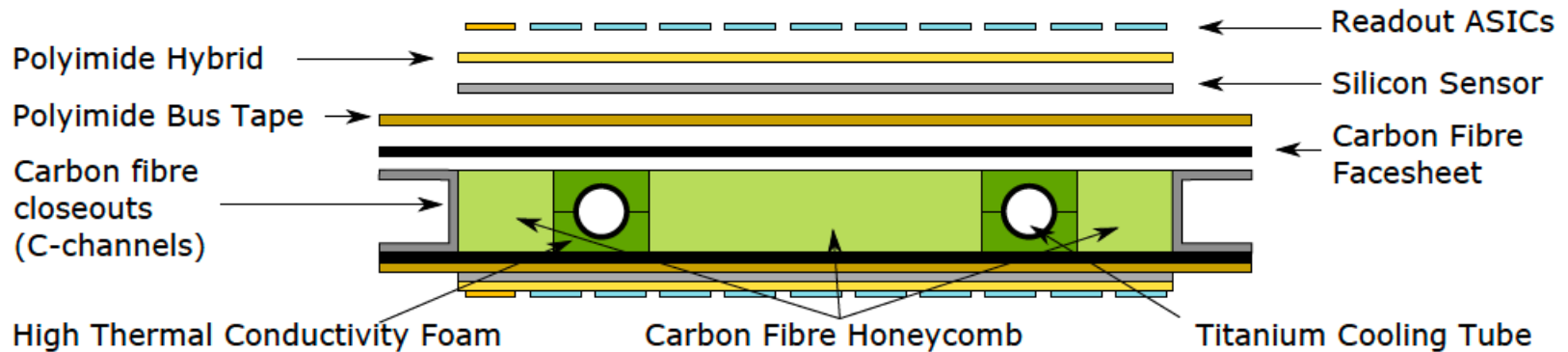


Table 9.4: Radiation length estimates for the barrel stave and end-cap petal. Power ASICs and the EoS are not included. These numbers need to be confirmed with full stave and petal designs.

Barrel		End-Cap	
Component	% Radiation Length	Component	% Radiation Length
Stave Core	0.48	Petal Core	0.46
Bus Cable	0.18	Bus cables	0.23
Short-Strip Modules	1.08	Modules	1.04
Module Adhesive	0.06	Module adhesive	0.05
Total	1.80	Total	1.78

DEMONSTRATOR MATERIAL BUDGET

Stavelet Demonstrator

Stave el	Comp	Material	Thick [um]	X0 [cm]	X0[%]
Module	FPC metal	Al (Cu)	50	8.896 (1.435)	0.056 (0.348)
	FPC insulat	Polyimide	100	28.41	0.035
	ASIC	Silicon	100 (150)	9.369	0.106 (0.160)
	Glue	Eccobond 45	100	44.37	0.023
	Total (Al and Si 100um)				0.22
Total (Al and Si 150um)				0.274	
Total (Cu and Si 150um)				0.566	
Everything else	Total				0.6
Total (Module Al and Si 100um)				0.82	
Total (Module Al and Si 150um)				0.874	
Total (Module Cu and Si 150um)				1.166	

ALICE Outer Layer Stave

Table 4.2: Estimated contributions of the Outer Layer Stave to the material budget.

Stave element	Component	Material	Thickness (μm)	X_0 (cm)	X_0 (%)
Module	FPC Metal layers	Aluminium	50	8.896	0.056
	FPC Insulating layers	Polyimide	100	28.41	0.035
	Module plate	Carbon fibre	120	26.08	0.046
	Pixel Chip	Silicon	50	9.369	0.053
	Glue	Eccobond 45	100	44.37	0.023
Power Bus	Metal layers	Aluminium	200	8.896	0.225
	Insulating layers	Polyimide	200	28.41	0.070
	Glue	Eccobond 45	100	44.37	0.023
Cold Plate		Carbon fleece	40	106.80	0.004
		Carbon paper	30	26.56	0.011
	Cooling tube wall	Polyimide	64	28.41	0.013
	Cooling fluid	Water		35.76	0.105
	Carbon plate	Carbon fibre	120	26.08	0.046
	Glue	Eccobond 45	100	44.37	0.023
Space Frame		Carbon rowing			0.080
Total					0.813

ALICE Inner Layer Stave

Table 4.1: Estimated contributions of the Inner Layer Stave to the material budget.

Stave element	Component	Material	Thickness (μm)	X_0 (cm)	X_0 (%)
HIC	FPC Metal layers	Aluminium	50	8.896	0.056
	FPC Insulating layers	Polyimide	100	28.41	0.035
	Pixel Chip	Silicon	50	9.369	0.053
Cold Plate		Carbon fleece	40	106.80	0.004
		Carbon paper	30	26.56	0.011
	Cooling tube wall	Polyimide	25	28.41	0.003
	Cooling fluid	Water		35.76	0.032
	Carbon plate	Carbon fibre	70	26.08	0.027
	Glue	Eccobond 45	100	44.37	0.023
Space Frame		Carbon rowing			0.018
Total					0.262

BEYOND THE DEMONSTRATOR

- Improved design over the ATLAS ITk-Strip stave structure (less material) or new design of a **long truss structure with sufficient rigidity**
 - Sufficient cooling capacity, alignment/monitoring with laser

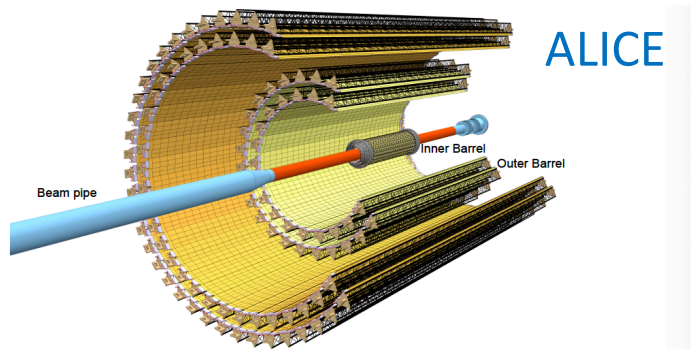
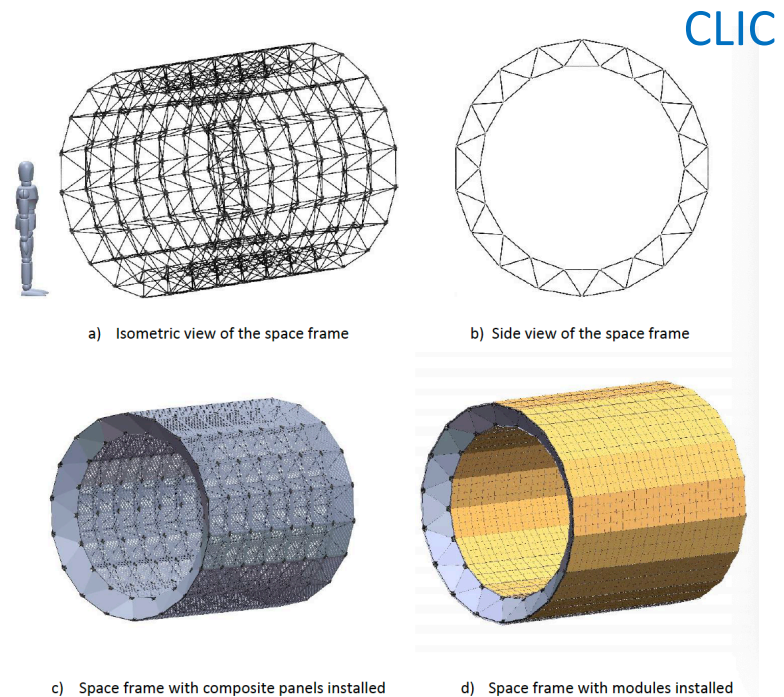
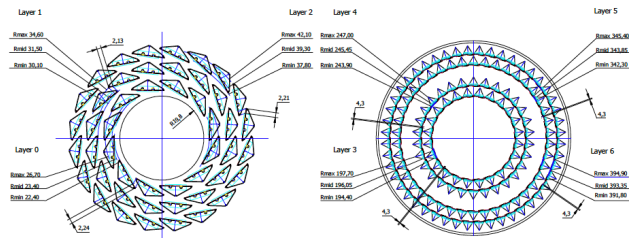
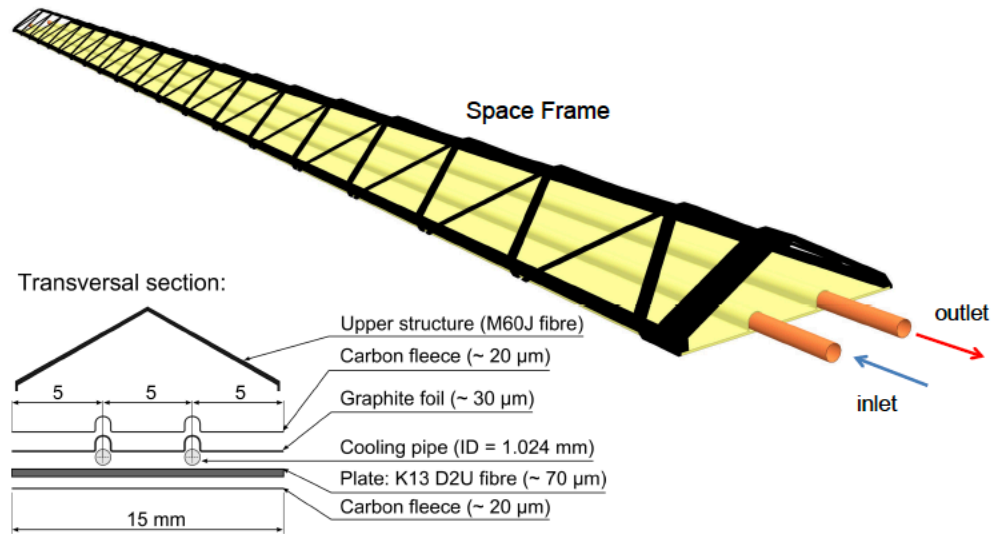
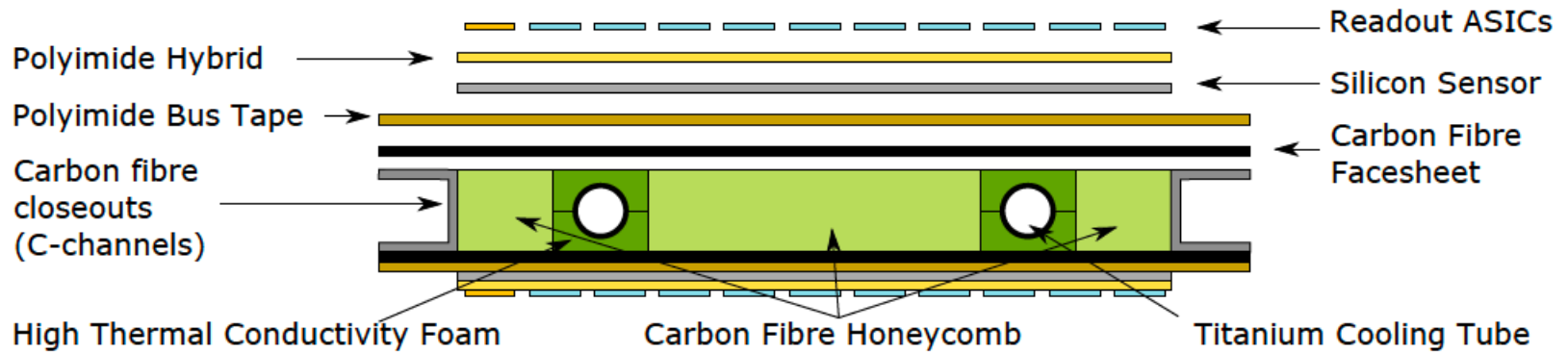


Figure 1.1: Layout of the new ITS detector.

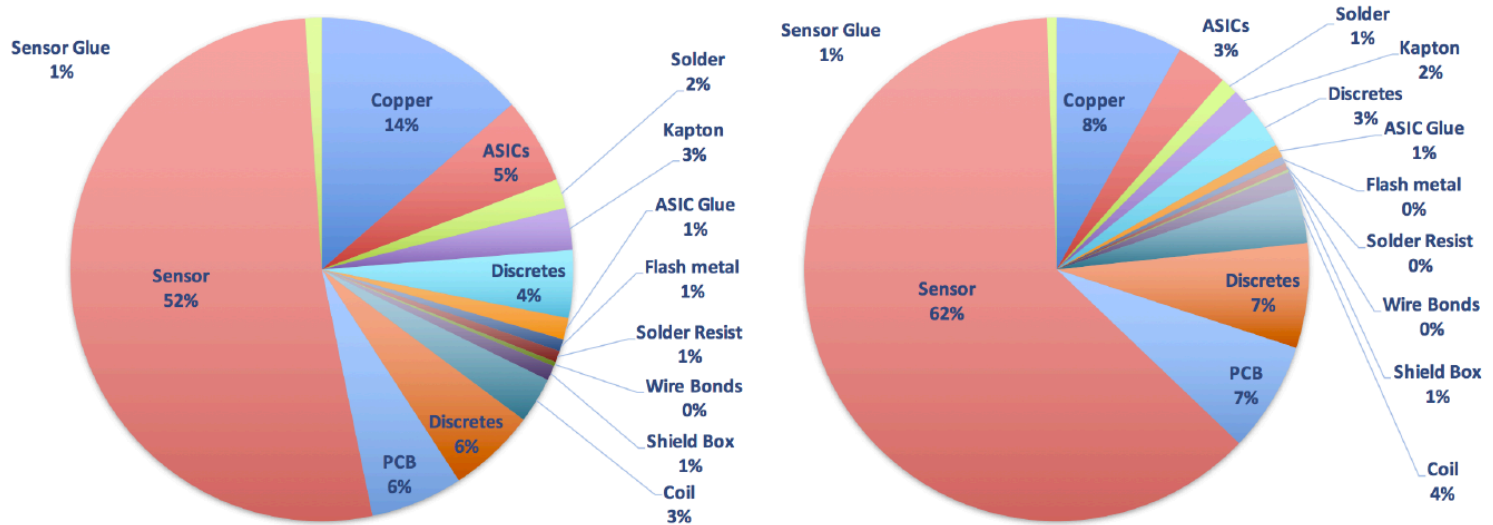


- Reliable power distribution, data/clock transmission over long distance

MODULE MATERIAL CALCULATION



MODULE MATERIAL CALCULATION



0.65% X₀

0.55% X₀

Figure 7.4: Fractional contributions for different materials to the radiation length of the barrel modules. Left: Short-strip barrel module. Right: Long-strip barrel module.